ENHANCED SPECIFICATION SURFACE MOUNT SILICON SCHOTTKY DIODE



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMDSH-4E is an enhanced version of the CMDSH-3 silicon Schottky diode in an SOD-323 surface mount package.

ENHANCED SPECIFICATIONS:

- ullet I $_{
 m O}$ from 100 mA MAX to 200 mA MAX
- $\bullet~{\rm BV}_{\rm R}$ from 30V MIN to 40V MIN
- $\bullet~V_F$ from 1.0 V MAX to 0.8 V MAX

MARKING CODE: S1E

	Central	
ENHANCED		
SPECIFICATION	SOD-323 CASE	

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
♦ Peak Repetitive Reverse Voltage	v_{RRM}	40	V
♦ Average Forward Current	Io	200	mA
Peak Repetitive Forward Current	I _{FRM}	350	mA
Peak Forward Surge Current, tp=10ms	I _{FSM}	750	mA
Power Dissipation	P_{D}	250	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	500	°C/W

ELECTRICA	L CHARACTERISTICS: (T _A =25°C unle	ss otherwise	noted)		
SYMBOL	TEST CONDITIONS	MIN	ΤΫ́Ρ	MAX	UNITS
I_{R}	V _R =25V		90	500	nA
I_{R}	V_R =25V, T_A =100°C		25	100	μΑ
♦ BV _R	I _R =100μA	40	50		V
V_{F}	I _F =2.0mA		0.29	0.33	V
• V _F	I _F =15mA		0.37	0.42	V
• V _F	I _F =100mA		0.51	0.80	V
• • v _F	I _F =200mA		0.65	1.0	V
CJ	V _R =1.0V, f=1.0MHz		7.0		pF
t _{rr}	$I_F = I_R = 10$ mA, $I_{rr} = 1.0$ mA, $R_L = 100$ Ω			5.0	ns

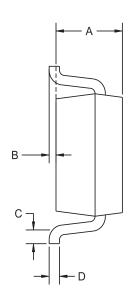
[•] Enhanced specification.

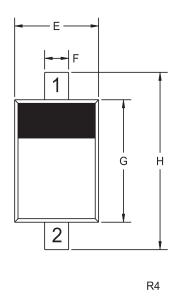
^{♦ ♦} Additional Enhanced specification.

ENHANCED SPECIFICATION SURFACE MOUNT SILICON **SCHOTTKY DIODE**



SOD-323 CASE - MECHANICAL OUTLINE





LEAD CODE:

- 1) Cathode 2) Anode

MARKING CODE: S1E

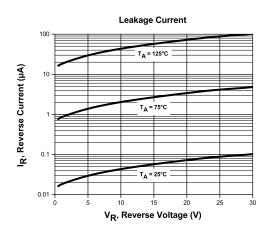
DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0.031	0.039	0.80	1.00		
В	0.000	0.004	0.00	0.10		
С	0.008	-	0.20	-		
D	0.004	0.007	0.11	0.19		
Е	0.045	0.053	1.15	1.35		
F	-	0.014	-	0.35		
G	0.063	0.071	1.60	1.80		
Н	0.094	0.102	2.40	2.60		

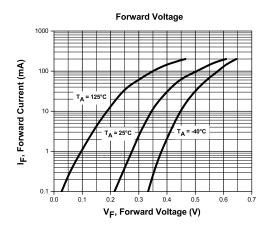
SOD-323 (REV: R4)

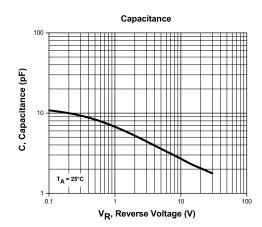
ENHANCED SPECIFICATION SURFACE MOUNT SILICON SCHOTTKY DIODE

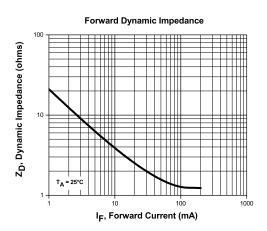


TYPICAL ELECTRICAL CHARACTERISTICS





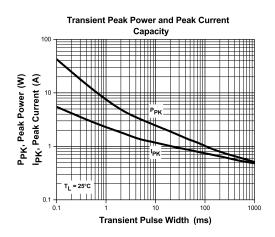


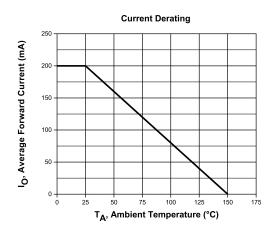


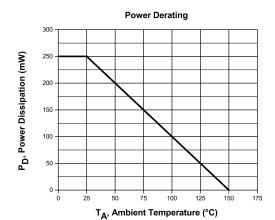




TYPICAL ELECTRICAL CHARACTERISTICS







OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- · Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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